

# SAC3106

GaAs MMIC Power Amplifier  
27GHz~33GHz 33dBm

Rev 2.1

## Features

- Frequency: 27GHz~33GHz
- Gain: 20dB
- Output P<sub>-1dB</sub>: 33dBm
- Output IP<sub>3</sub>: 38dBm
- Supply Voltage: +6V
- Power-Added Efficiency: 22%
- Die Size: 3.18mm×2.46mm×0.1mm

## Typical Applications

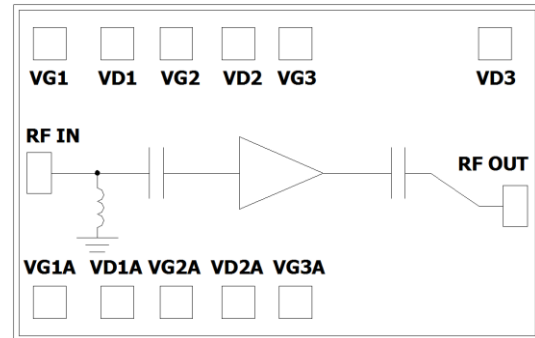
- Point-to-Point Radios
- SATCOM
- Military and Space
- Test and Measurement
- Radar

## General Description

SAC3106 is a wideband GaAs MMIC power amplifier which operates between 27GHz~33GHz. The SAC3106 provides 20dB of gain, +33 dBm of output power for 1 dB compression and 22% PAE from a +6V supply.

SAC3106 offers full passivation for increased reliability and moisture protection.

## Functional Diagram



## Electrical Performance (T<sub>A</sub>=25°C, V<sub>D</sub>=+6V, I<sub>D</sub>=1000mA, Z<sub>0</sub>=50Ω)

Parameter	Min.	Typ.	Max.	Units
Frequency Range	27~33			GHz
Small Signal Gain	15	20	—	dB
Small Signal Gain Flatness	—	±2.5	—	dB
Reverse Isolation	—	-45	—	dB
Input Return Loss	—	-10	—	dB
Output Return Loss	—	-13	—	dB
Power-Added Efficiency	—	22	—	%
Output Power for 1 dB Compression (OP <sub>-1dB</sub> )	31.5	33	—	dBm
Output Third Order Intercept (OIP <sub>3</sub> ) *	—	38	—	dBm
Drain Voltage (V <sub>D</sub> )	5	—	6	V
Supply Current (I <sub>D</sub> )	—	1000	1600	mA

\* Measurement taken at P<sub>out</sub> / Tone = +28 dBm

## Absolute Maximum Ratings

Maximum Input Power	+19dBm	Operating Temperature	-55°C~+85°C
Channel Temperature	+150°C	Storage Temperature	-65°C~+150°C
Maximum V <sub>D</sub>	+6.5V	Maximum V <sub>G</sub>	-1.2V

## SuperApex, LLC

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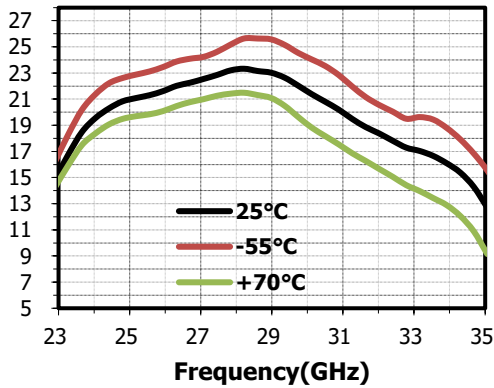
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## Typical Performance Curve

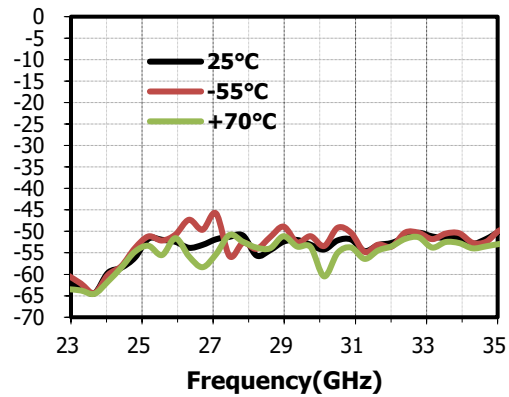
S-parameter Data obtained from On-Wafer RF Probe Test Results  
OP<sub>1</sub>dB and PAE Data obtained from K connector-based test fixture

\*Bias Conditions: V<sub>D</sub> =6V, I<sub>D</sub> =1000mA

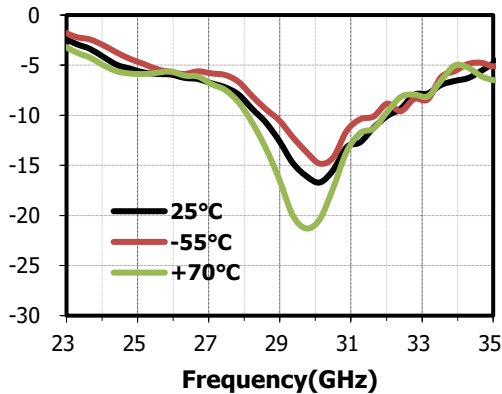
Small Signal Gain(dB) vs.Temperature



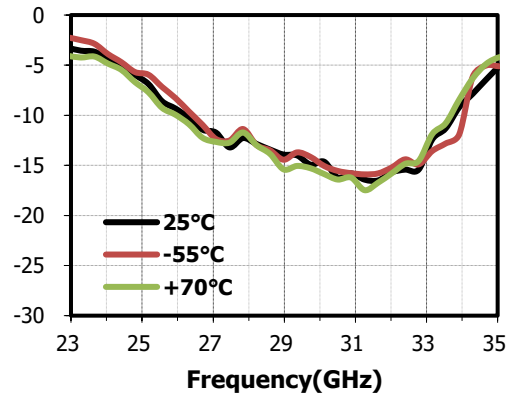
Reverse Isolation(dB) vs.Temperature



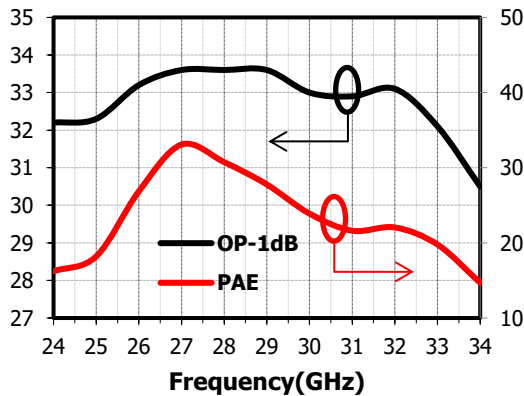
Input Return Loss(dB) vs.Temperature



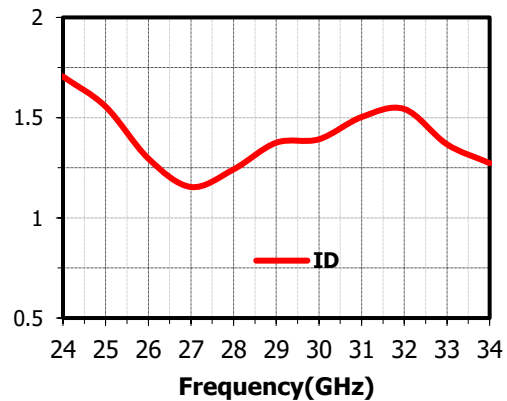
Output Return Loss(dB) vs.Temperature



OP<sub>1</sub>dB(dBm), PAE(%) vs.Freq



I<sub>D</sub>(A) vs.Freq@OP<sub>1</sub>dB



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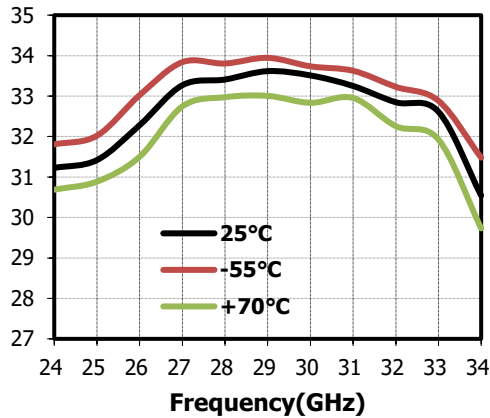
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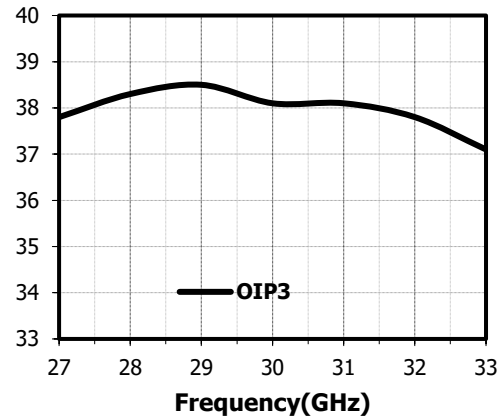
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**OP-1dB vs. Temperature**

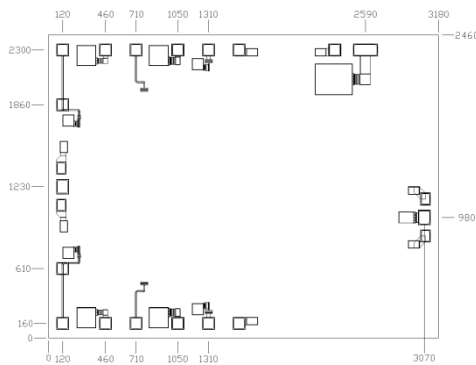


**OIP3(dBm), P<sub>OUT</sub>/Tone=28dBm vs. Freq**

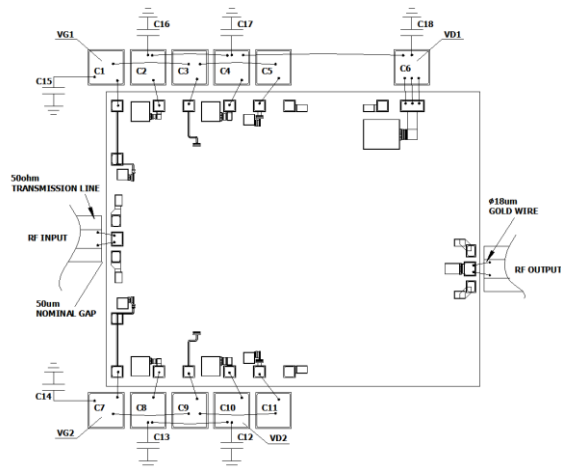


**Die Outline**

(All dimensions in  $\mu\text{m}$ )



**Assembly Diagram**



VG1~VG3、VD1~VD2 Bonding Pad Size: 100x100 $\mu\text{m}$   
 VG1A~VG3A、VD1A~VD2A Bonding Pad  
 Size: 100x100 $\mu\text{m}$   
 RF IN、RF OUT Bonding Pad Size: 100x120 $\mu\text{m}$   
 VD3 Bonding Pad Size: 200x100 $\mu\text{m}$

## Components List

Reference Des.	Value	Part Number	Manuf.	Size
C12~C18	4.7 $\mu\text{F}$	GRM155R61A475KE15D	Murata	0402
C1~C11	100pF	—	ANY	SLC

## Notes

- SAC3106 is biased with a positive drain voltage supply and negative gate voltage supply when the drain voltage is set to 6 V. The recommended gate voltage is set to -0.5~-0.8V.
- RF connections should be made as short as possible to reduce the inductive effect of the bond wire.
- The backside of SAC3106 is RF grounded. Die attach should be accomplished with electrically and thermally conductive epoxy only.
- Bypass caps C12~C18 should be placed no farther than 1.5mm from the amplifier.